

Excitonic properties of hBN from a time-dependent Hartree-Fock mean-field theory

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Escola de Ciências

Introduction

Main objective:

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Specific to a given:

- System's degrees of freedom
- Electronic model for the single-particle states
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- Numerical implementation of eigenproblem

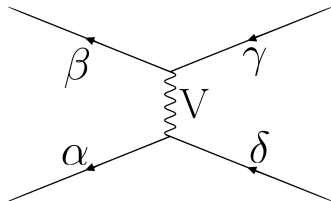
Theoretical description of excitons

Time-dependent Hartree-Fock mean-field theory

Time-dependent Hartree-Fock mean-field theory

Many-body system of electrons

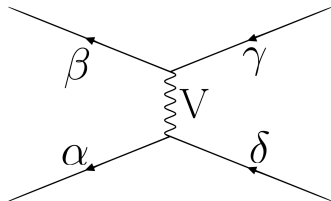
$$H_{\text{eq}} = \sum_{\alpha\beta} h_{\alpha\beta} c_{\alpha}^{\dagger} c_{\beta} + \frac{1}{2} \sum_{\alpha\beta\gamma\delta} v_{\gamma\delta}^{\alpha\beta} c_{\alpha}^{\dagger} c_{\beta}^{\dagger} c_{\gamma} c_{\delta}$$



Time-dependent Hartree-Fock mean-field theory

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External perturbation

$$H_{\text{ext}} = \sum_{\alpha\beta} B_{\alpha\beta} c_{\alpha}^{\dagger} c_{\beta} F(t)$$

Reduced density matrix

$$\rho_{ba}(t) = \langle c_a^\dagger(t) c_b(t) \rangle$$

Time-dependent Hartree-Fock mean-field theory

Reduced density matrix

$$\rho_{ba}(t) = \langle c_a^\dagger(t) c_b(t) \rangle$$

$$\frac{d}{dt} \rho_{ab}(t) = \frac{i}{\hbar} \langle [H, c_b^\dagger(t)] c_a(t) \rangle + \frac{i}{\hbar} \langle c_b^\dagger(t) [H, c_a(t)] \rangle$$

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$$\begin{aligned} -i\hbar \frac{d}{dt} \rho_{ab}(t) &= \rho_{a\alpha}(t) (h_{\alpha b} + B_{\alpha b}^i F^i(t)) - (h_{a\beta} + B_{a\beta}^i F^i(t)) \rho_{\beta b}(t) \\ &+ \frac{1}{2} V_{\gamma b}^{\alpha\beta} \langle c_\alpha^\dagger c_\beta^\dagger c_\gamma c_a \rangle - \frac{1}{2} V_{b\delta}^{\alpha\beta} \langle c_\alpha^\dagger c_\beta^\dagger c_\delta c_a \rangle \\ &+ \frac{1}{2} V_{\gamma\delta}^{\alpha a} \langle c_b^\dagger c_\alpha^\dagger c_\gamma c_\delta \rangle - \frac{1}{2} V_{\gamma\delta}^{a\beta} \langle c_b^\dagger c_\beta^\dagger c_\gamma c_\delta \rangle \end{aligned}$$

Mean-field decoupling

$$\langle c_{\alpha}^{\dagger} c_{\beta}^{\dagger} c_{\gamma} c_{\delta} \rangle \approx -\rho_{\gamma\alpha}(t)\rho_{\delta\beta}(t) + \rho_{a\alpha}(t)\rho_{\gamma\beta}(t)$$

Time-dependent Hartree-Fock mean-field theory

Mean-field decoupling

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$$i\hbar \frac{d}{dt} \rho(t) = [\mathbf{h} + \mathbf{B} \cdot \mathbf{F}(t) + \mathbf{\Sigma}^H[\rho(t)] + \mathbf{\Sigma}^F[\rho(t)], \rho(t)]$$

Time-dependent Hartree-Fock mean-field theory

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Hartree and Fock self-energy terms



$$\Sigma_{a\gamma}^H[\rho(t) - \rho^{(0)}] = V_{\delta\gamma}^{a\alpha} \rho_{\delta\alpha}(t)$$

$$\Sigma_{a\gamma}^F[\rho(t) - \rho^{(0)}] = -W_{\gamma\delta}^{a\alpha} \rho_{\delta\alpha}(t)$$



Time-dependent Hartree-Fock mean-field theory

Linear response in the single-particle eigenbasis at zero temperature

$$\rho(t) \approx \rho^{(0)} + \rho^{(1)}(t) \quad | \quad \begin{array}{l} h_{ac} = \epsilon_a \delta_{ac} \\ \rho_{ab}^{(0)} = f_a \delta_{ab} \end{array} \quad | \quad \begin{array}{l} f_o = 1 \\ f_e = 0 \end{array}$$

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$$(\hbar\omega \mathbf{S} - \mathbf{H}_{e-h}) \rho^{(1)}(\omega) = \mathbf{S} \mathcal{J}(\omega)$$

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Effective two-particle Hamiltonian

$$\mathbf{H}_{e-h} = \begin{bmatrix} \mathbf{R} & \mathbf{C} \\ \mathbf{C}^\dagger & \mathbf{R}^* \end{bmatrix} \stackrel{\text{TDA}}{\approx} \mathbf{R}$$

Resonant Block

$$\mathbf{R} \equiv H_{e_1 o_2}^{e_3 o_4} = (\epsilon_{e_1} - \epsilon_{o_2}) \delta_{e_1 e_3} \delta_{o_2 o_4} + (V_{o_2 e_3}^{o_4 e_1} - W_{o_2 e_3}^{e_1 o_4})$$

Linear response eigenvalue solution

Linear response eigenvalue solution

$$(\hbar\omega\mathbf{S} - \mathbf{H}_{e-h}) \cdot \Psi_\lambda = E_\lambda \Psi.$$

Excitonic generalized eigen-problem

$$\mathbf{H}_{e-h} \cdot \Psi_X = E_X \mathbf{S} \cdot \Psi_X$$

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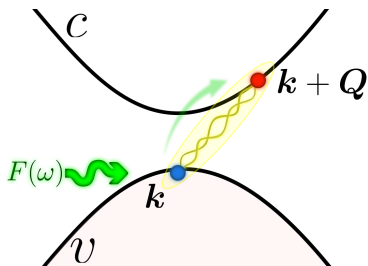
$$\rho^{(1)}(\omega) = \sum_X a_X(\omega) \Psi_X$$

Reduced density matrix solution

$$\rho^{(1)}(\omega) = \sum_X \Psi_X \frac{\text{sign}(E_X)}{(\hbar\omega - E_X)} \Psi_X \cdot \mathbf{S} \cdot \mathbf{B}F(\omega)$$

Excitonic generalized eigen-problem in a crystal

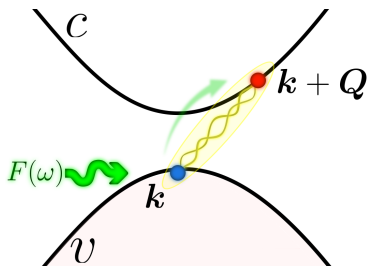
Excitonic generalized eigen-problem in a crystal



Structure in the Bloch
momentum degree of freedom

$$\mathcal{J}_{\{k+Q\}_{c_1, kv_2}}(\omega, Q + G)$$

Excitonic generalized eigen-problem in a crystal

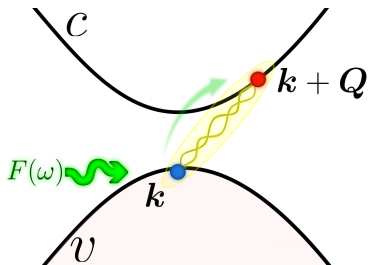


Structure in the Bloch momentum degree of freedom

$$\mathcal{J}_{\{k+Q\}_{c_1, kv_2}}(\omega, Q + G)$$

$$H_{e-h} \stackrel{\text{TDA}}{\approx} R_{k,k'}(Q) = H_{\{k+Q\}_{c_1, kv_2}}^{\{k'+Q\}_{c_3, k'v_4}}$$

Excitonic generalized eigen-problem in a crystal

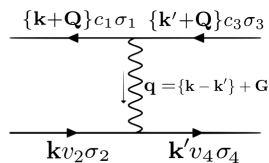
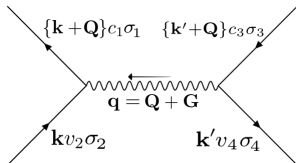
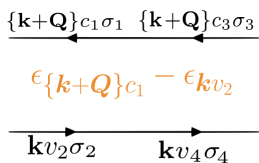


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Free (ϵ) + Hartree (V) — Fock (W)



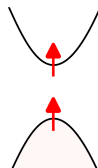
Structure in the spin degree of freedom

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Spin-singlet set of solutions

$$|s\rangle = (1/\sqrt{2}) (|c \uparrow, v \uparrow\rangle + |c \downarrow, v \downarrow\rangle)$$

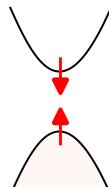
$$R_s = \epsilon - W + 2V$$



Spin-triplet set of solutions

$$|t\rangle = |c \uparrow, v \downarrow\rangle, |c \downarrow, v \uparrow\rangle, (1/\sqrt{2}) (|c \uparrow, v \uparrow\rangle - |c \downarrow, v \downarrow\rangle)$$

$$R_t = \epsilon - W$$

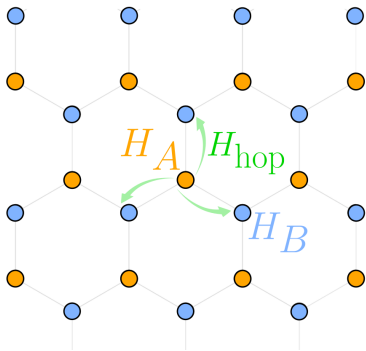


$$\epsilon := (\epsilon_{\{k+Q\}c_1} - \epsilon_{kv_2}), \quad W := W_{kv_2, \{k'+Q\}c_3}^{\{k+Q\}c_1, k'v_4}, \quad V := V_{kv_2, \{k'+Q\}c_3}^{k'v_4, \{k+Q\}c_1}$$

Excitons on hBN structures

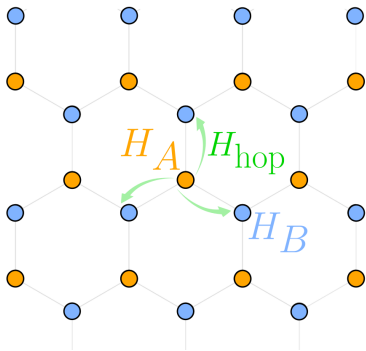
Electronic single-particle states - NN tight-binding model

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$$H_{\text{TB}} = \sum_i \epsilon_A a_{\mathbf{R}_i}^\dagger a_{\mathbf{R}_i} + \sum_i \epsilon_B b_{\mathbf{R}_i}^\dagger b_{\mathbf{R}_i} - t \sum_{\langle i,j \rangle} \left(a_{\mathbf{R}_i}^\dagger b_{\mathbf{R}_i + \delta_j} + b_{\mathbf{R}_j}^\dagger a_{\mathbf{R}_i - \delta_j} \right)$$

Electronic single-particle states - NN tight-binding model

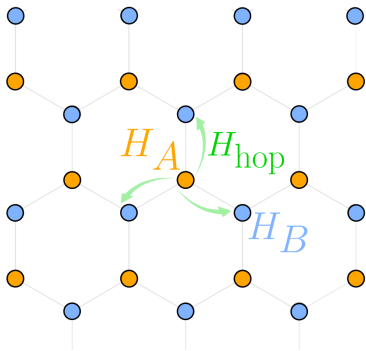


$$\gamma_{\mathbf{k}} = \sum_{\langle j \rangle} e^{+i\mathbf{k} \cdot \delta_j}$$

$$H_{\text{TB}}(\mathbf{k}) = \begin{bmatrix} \epsilon_A & -t\gamma_{\mathbf{k}} \\ -t\gamma_{\mathbf{k}}^\dagger & \epsilon_B \end{bmatrix}$$

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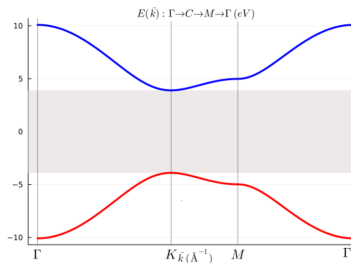
Electronic single-particle states - NN tight-binding model



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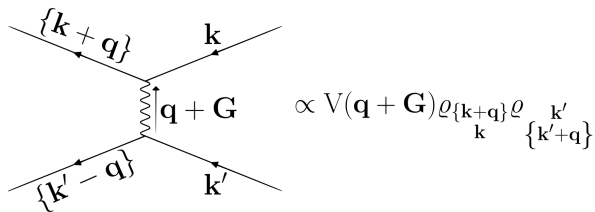
Electron-electron interaction - Atomistic model

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$$H_{e-e} = \sum_{\substack{\mathbf{R}_1 \mathbf{R}_2 \\ \varsigma_1 \varsigma_2}} V((\mathbf{R}_1 + \mathbf{s}_{\varsigma_1}) - (\mathbf{R}_2 + \mathbf{s}_{\varsigma_2})) c_{\mathbf{R}_1 \varsigma_1}^\dagger c_{\mathbf{R}_2 \varsigma_2}^\dagger c_{\mathbf{R}_2 \varsigma_2} c_{\mathbf{R}_1 \varsigma_1}$$

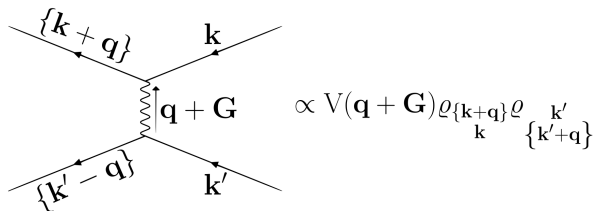
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Coulomb Potential

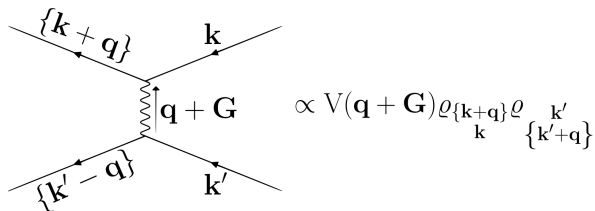
$$V_{2D}(\mathbf{k}) = \frac{e^2}{2\epsilon_0} \frac{1}{|\mathbf{k}|}$$

Rytova-Keldysh Potential

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Static limit

$$W(\omega = 0)$$

Quick recap

&

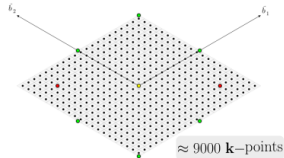
Numerical implementation

Implementing the electron-hole Hamiltonian

Implementing the electron-hole Hamiltonian

$$H_{e-h}(\mathbf{Q}) = \left[\begin{array}{c} R \left\{ \begin{array}{l} \mathbf{k}'_1 + \mathbf{Q} \\ \mathbf{k}_1 + \mathbf{Q} \end{array} \right\} \begin{array}{l} c_{3, \mathbf{k}'_1} v_4 \\ c_{1, \mathbf{k}_1} v_2 \end{array} \\ \downarrow \mathbf{k} \end{array} \quad \begin{array}{l} \mathbf{k}' \\ \dots \end{array} \right]$$

Discretization of the hBN 1BZ

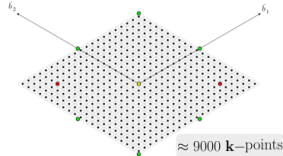


Implementing the electron-hole Hamiltonian

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Fixed excitonic
center of mass
momentum

Discretization of the hBN 1BZ

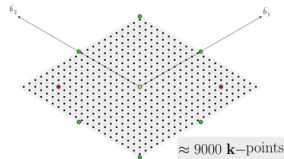


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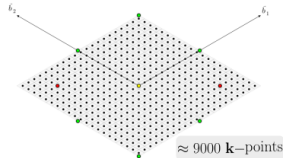
$$\begin{aligned} & \left(\epsilon_{\{\mathbf{k}+\mathbf{Q}\}c_1} - \epsilon_{\mathbf{k}v_2} \right) \delta_{\{\mathbf{k}+\mathbf{Q}\}c_1, \{\mathbf{k}'+\mathbf{Q}\}c_3} \delta_{\mathbf{k}v_2, \mathbf{k}'v_4} \\ & + \left(V_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\mathbf{k}'v_4, \{\mathbf{k}+\mathbf{Q}\}c_1} - W_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\{\mathbf{k}+\mathbf{Q}\}c_1, \mathbf{k}'v_4} \right) \end{aligned}$$

Implementing the electron-hole Hamiltonian

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Fixed excitonic
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Discretization of the hBN 1BZ



$$\begin{aligned} & \left(\epsilon_{\{\mathbf{k}+\mathbf{Q}\}c_1} - \epsilon_{\mathbf{k}v_2} \right) \delta_{\{\mathbf{k}+\mathbf{Q}\}c_1, \{\mathbf{k}'+\mathbf{Q}\}c_3} \delta_{\mathbf{k}v_2, \mathbf{k}'v_4} \\ & + \left(V_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\mathbf{k}'v_4, \{\mathbf{k}+\mathbf{Q}\}c_1} - W_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\{\mathbf{k}+\mathbf{Q}\}c_1, \mathbf{k}'v_4} \right) \end{aligned}$$

$\epsilon_{\mathbf{k}\lambda}$

$\phi_{\mathbf{k}\lambda}^s$

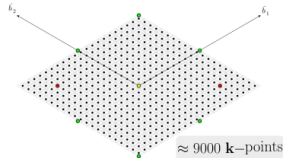
$\mathbf{H}_{TB}(\mathbf{k})$

Electronic single-
particle properties

Implementing the electron-hole Hamiltonian

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Discretization of the hBN 1BZ



Fixed excitonic center of mass momentum

$$\begin{aligned} & (\epsilon_{\{\mathbf{k}+\mathbf{Q}\}c_1} - \epsilon_{\mathbf{k}v_2}) \delta_{\{\mathbf{k}+\mathbf{Q}\}c_1, \{\mathbf{k}'+\mathbf{Q}\}c_3} \delta_{\mathbf{k}v_2, \mathbf{k}'v_4} \\ & + \left(V_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\mathbf{k}'v_4, \{\mathbf{k}+\mathbf{Q}\}c_1} - W_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\{\mathbf{k}+\mathbf{Q}\}c_1, \mathbf{k}'v_4} \right) \end{aligned}$$

$\epsilon_{\mathbf{k}\lambda}$

$\phi_{\mathbf{k}\lambda}^s$

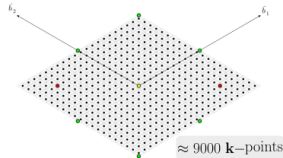
$\mathbf{H}_{TB}(\mathbf{k})$

Electronic single-particle properties

Implementing the electron-hole Hamiltonian

$$H_{e-h}(\mathbf{Q}) = \left[\begin{array}{c} R \left\{ \begin{array}{l} \mathbf{k}'_1 + \mathbf{Q} \\ \mathbf{k}_1 + \mathbf{Q} \end{array} \right\} \begin{array}{l} c_3, \mathbf{k}'_1 v_4 \\ c_1, \mathbf{k}_1 v_2 \end{array} \\ \downarrow \mathbf{k} \end{array} \quad \begin{array}{l} \mathbf{k}' \\ \vdots \end{array} \right]$$

Discretization of the hBN 1BZ



Fixed excitonic center of mass momentum

$$\begin{aligned} & (\epsilon_{\{\mathbf{k}+\mathbf{Q}\}c_1} - \epsilon_{\mathbf{k}v_2}) \delta_{\{\mathbf{k}+\mathbf{Q}\}c_1, \{\mathbf{k}'+\mathbf{Q}\}c_3} \delta_{\mathbf{k}v_2, \mathbf{k}'v_4} \\ & + \left(V_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\mathbf{k}'v_4, \{\mathbf{k}+\mathbf{Q}\}c_1} - W_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\{\mathbf{k}+\mathbf{Q}\}c_1, \mathbf{k}'v_4} \right) \end{aligned}$$

$\epsilon_{\mathbf{k}\lambda}$

$\phi_{\mathbf{k}\lambda}^s$

$\mathbf{H}_{TB}(\mathbf{k})$

Electronic single-particle properties

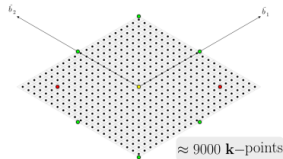
$$\varrho_{\mathbf{k}\lambda, \mathbf{k}'\lambda'}^{\mathbf{p}} = \sum_s e^{i(\mathbf{k}' - \mathbf{k} + \mathbf{p}) \cdot \mathbf{s}_s} (\phi_{\mathbf{k}\lambda}^s)^* \phi_{\mathbf{k}'\lambda'}^s$$

Atomistic electron-electron interaction form factors

Implementing the electron-hole Hamiltonian

Discretization of the hBN 1BZ

$$H_{e-h}(\mathbf{Q}) = \begin{bmatrix} R \left\{ \begin{matrix} \mathbf{k}'_1 + \mathbf{Q} \\ \mathbf{k}_1 + \mathbf{Q} \end{matrix} \right\} \begin{matrix} c_3, \mathbf{k}'_1 v_4 \\ c_1, \mathbf{k}_1 v_2 \end{matrix} & \mathbf{k}' \\ \downarrow \mathbf{k} & \dots \end{bmatrix}$$



Fixed excitonic center of mass momentum

$$\begin{aligned} & (\epsilon_{\{\mathbf{k}+\mathbf{Q}\}c_1} - \epsilon_{\mathbf{k}v_2}) \delta_{\{\mathbf{k}+\mathbf{Q}\}c_1, \{\mathbf{k}'+\mathbf{Q}\}c_3} \delta_{\mathbf{k}v_2, \mathbf{k}'v_4} \\ & + \left(V_{\mathbf{k}v_2, \{\mathbf{k}+\mathbf{Q}\}c_1}^{\mathbf{k}'v_4, \{\mathbf{k}'+\mathbf{Q}\}c_3} - W_{\mathbf{k}v_2, \{\mathbf{k}'+\mathbf{Q}\}c_3}^{\{\mathbf{k}+\mathbf{Q}\}c_1, \mathbf{k}'v_4} \right) \end{aligned}$$

$\epsilon_{\mathbf{k}\lambda}$

$\phi_{\mathbf{k}\lambda}^s$

$\mathbf{H}_{TB}(\mathbf{k})$

Electronic single-particle properties

$$V(\mathbf{k}) = \frac{e^2}{2\epsilon_0 |\mathbf{k}|}$$

Bare Coulomb

$$W(\mathbf{k}) = \frac{e^2}{2\epsilon_0 |\mathbf{k}|} \frac{1}{1+r_0|\mathbf{k}|}$$

Rytova-Keldysh

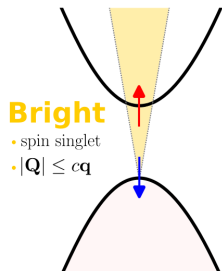
$$\varrho_{\mathbf{k}\lambda, \mathbf{k}'\lambda'}^{\mathbf{p}} = \sum_s e^{i(\mathbf{k}' - \mathbf{k} + \mathbf{p}) \cdot \mathbf{s}_s} (\phi_{\mathbf{k}\lambda}^s)^* \phi_{\mathbf{k}'\lambda'}^s$$

Atomistic electron-electron interaction form factors

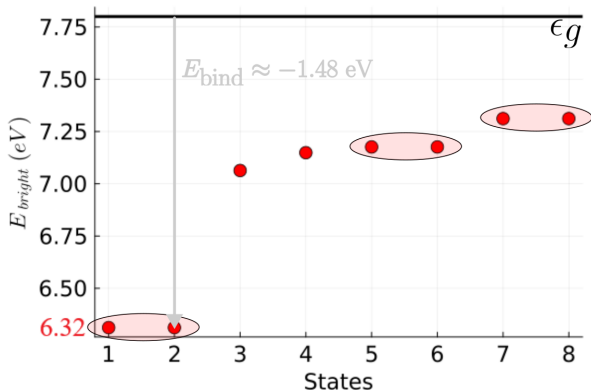
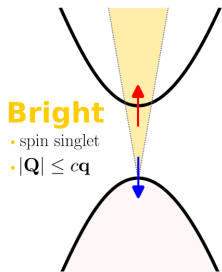
Results for the excitonic energy band-structure and wave-functions

Isolated hBN monolayer: Spin-singlet with $Q = 0$

Isolated hBN monolayer: Spin-singlet with $\mathbf{Q} = 0$



Isolated hBN monolayer: Spin-singlet with $Q = 0$

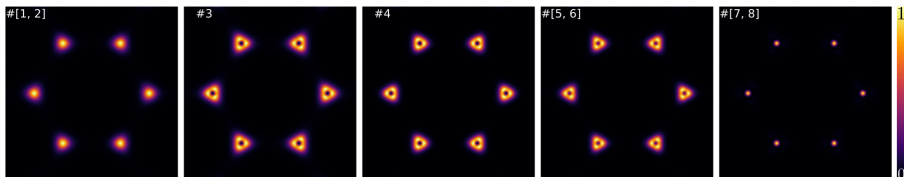


T. Galvani, Phys. Rev. B 94 (2016): $E_{\text{bind}} = -1.93$ eV

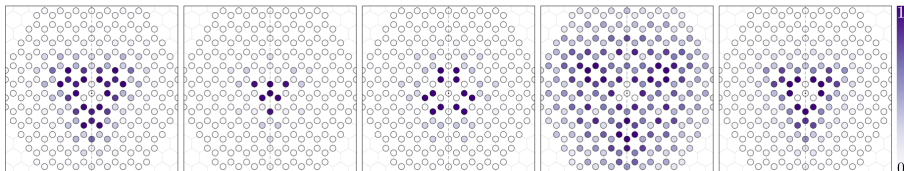
Quintela, Phys. Status Solidi. B 259(7) (2022): $E_{\text{bind}} = -1.31$ eV

Isolated hBN monolayer: Spin-singlet with $Q = 0$

In reciprocal space:

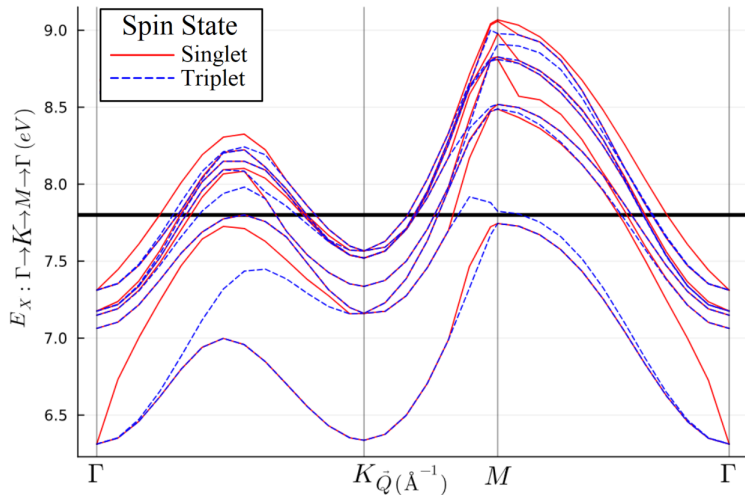


In real space:

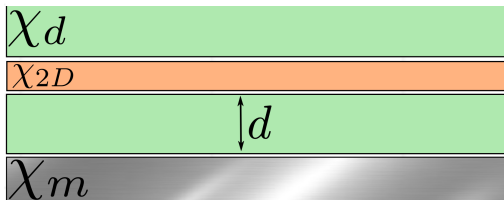


Isolated hBN monolayer: band structure

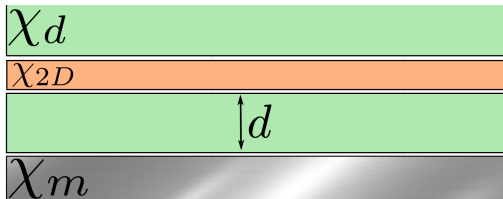
Isolated hBN monolayer: band structure



hBN-metal hetero-structure



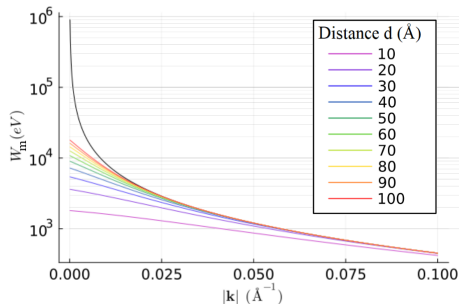
hBN-metal hetero-structure



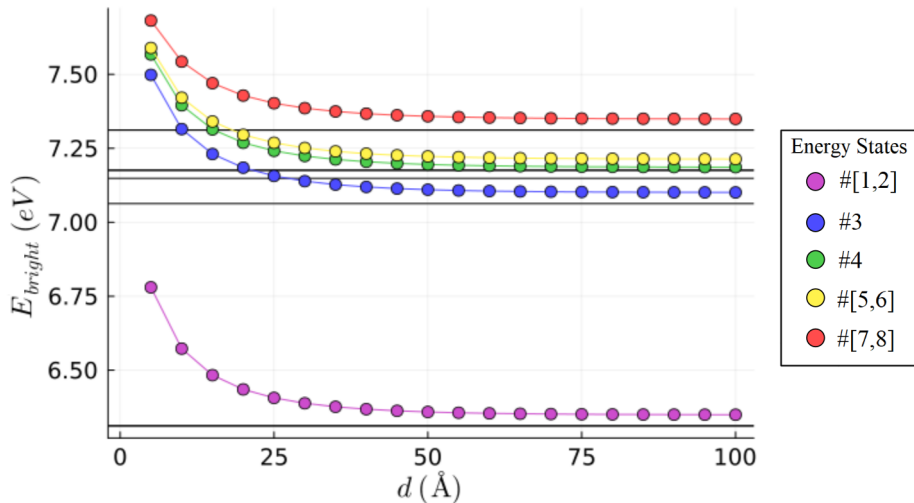
Metal-screened Rytova-Keldysh

$$W_m(\mathbf{k}) = \frac{e}{2\epsilon_0} \frac{1}{k} \frac{1}{r_0 k + \frac{1}{2} \frac{e^{kd}}{\sinh(kd)}}$$

For metal-screened Coulomb set $r_0 = 0$



hBN-metal hetero-structure: Spin-singlet with $Q = 0$



Conclusions

&

Future works

Formulated a method to calculate excitonic energies and wave-function

- Simple yet effective:
 - Easy to compute
 - Relatively small computational time
 - Precision up to 2 decimal places (scaling with \mathbf{k} -point sampling)
 - Results within reason when comparing to more challenging techniques
- Versatile in the:
 - System's degrees of freedom (could account for spin-orbit effects or three-band models with some additional tweaks)
 - Electronic model to the single particle electronic states
 - Electron-electron interaction
 - Choice of electrostatic potential (different types of screenings)

Future work...

Generalized susceptibility

$$\chi_{AB}(\omega) = \frac{\langle A \rangle(\omega)}{F(\omega)} = \frac{\sum_{ab} A_{ab} \rho_{ba}^{(1)}(\omega)}{F(\omega)}$$

Optical conductivity

Exciton life-times

Generalized susceptibility

$$\chi_{AB}(\omega) = \frac{\langle A \rangle(\omega)}{F(\omega)} = \frac{\sum_{ab} A_{ab} \rho_{ba}^{(1)}(\omega)}{F(\omega)}$$

Optical conductivity

Exciton life-times

Dependence on the screening effective radius

Dependence on the dielectric of the hetero-structure

Generalized susceptibility

$$\chi_{AB}(\omega) = \frac{\langle A \rangle(\omega)}{F(\omega)} = \frac{\sum_{ab} A_{ab} \rho_{ba}^{(1)}(\omega)}{F(\omega)}$$

Optical conductivity

Exciton life-times

Dependence on the screening effective radius

Dependence on the dielectric of the hetero-structure

Three-band model TMDs

Thank you for listening!

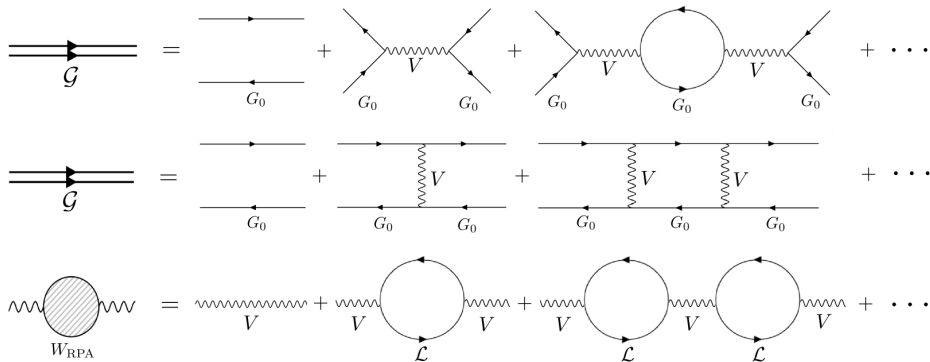
Any questions?

The author acknowledges funding from Fundação para a Ciência e a Tecnologia (FCT-Portugal) through grant No. EXPL/FIS-MAC/0953/2021.



Fundação
para a Ciência
e a Tecnologia

More on the screening of the Hartree and the Fock terms...



More on the structure in the spin degree of freedom...

$$\left(\hbar\omega \mathbb{1} - \begin{bmatrix} R_{\uparrow 3 \uparrow 4}^{\uparrow 1 \uparrow 2} & R_{\uparrow 3 \downarrow 4}^{\uparrow 1 \uparrow 2} & R_{\downarrow 3 \uparrow 4}^{\uparrow 1 \uparrow 2} & R_{\downarrow 3 \downarrow 4}^{\uparrow 1 \uparrow 2} \\ R_{\uparrow 3 \uparrow 4}^{\downarrow 1 \uparrow 2} & R_{\uparrow 3 \downarrow 4}^{\downarrow 1 \uparrow 2} & R_{\downarrow 3 \uparrow 4}^{\downarrow 1 \uparrow 2} & R_{\downarrow 3 \downarrow 4}^{\downarrow 1 \uparrow 2} \\ R_{\uparrow 3 \uparrow 4}^{\uparrow 1 \downarrow 2} & R_{\uparrow 3 \downarrow 4}^{\uparrow 1 \downarrow 2} & R_{\downarrow 3 \uparrow 4}^{\uparrow 1 \downarrow 2} & R_{\downarrow 3 \downarrow 4}^{\uparrow 1 \downarrow 2} \\ R_{\uparrow 3 \uparrow 4}^{\downarrow 1 \downarrow 2} & R_{\uparrow 3 \downarrow 4}^{\downarrow 1 \downarrow 2} & R_{\downarrow 3 \uparrow 4}^{\downarrow 1 \downarrow 2} & R_{\downarrow 3 \downarrow 4}^{\downarrow 1 \downarrow 2} \end{bmatrix} \right) \begin{bmatrix} \rho_{c_3 \uparrow 3, v_4 \uparrow 4}^{(1)} \\ \rho_{c_3 \uparrow 3, v_4 \downarrow 4}^{(1)} \\ \rho_{c_3 \downarrow 3, v_4 \uparrow 4}^{(1)} \\ \rho_{c_3 \downarrow 3, v_4 \downarrow 4}^{(1)} \end{bmatrix} = \begin{bmatrix} \mathcal{J}_{c_1 \uparrow 1, v_2 \uparrow 2} \\ \mathcal{J}_{c_1 \uparrow 1, v_2 \downarrow 2} \\ \mathcal{J}_{c_1 \downarrow 1, v_2 \uparrow 2} \\ \mathcal{J}_{c_1 \downarrow 1, v_2 \downarrow 2} \end{bmatrix}$$

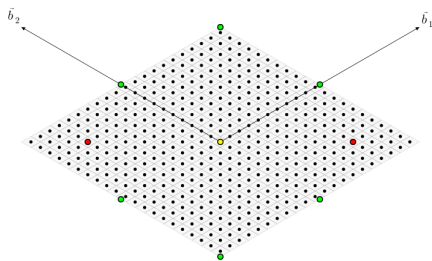
More on the structure in the spin degree of freedom...

$$\mathbf{R} = \begin{bmatrix} \epsilon + V - W & 0 & 0 & V \\ 0 & \epsilon - W & 0 & 0 \\ 0 & 0 & \epsilon - W & 0 \\ V & 0 & 0 & \epsilon + V - W \end{bmatrix} \begin{array}{l} \uparrow\uparrow \\ \uparrow\downarrow \\ \downarrow\uparrow \\ \downarrow\downarrow \end{array}$$

$$\epsilon := (\epsilon_{\{\mathbf{k}+\mathbf{Q}\}_{c_1}} - \epsilon_{kv_2}), \quad W := W_{kv_2, \{\mathbf{k}+\mathbf{Q}\}_{c_3}}^{\{\mathbf{k}+\mathbf{Q}\}_{c_1}, \mathbf{k}'v_4}, \quad V := V_{kv_2, \{\mathbf{k}+\mathbf{Q}\}_{c_3}}^{\mathbf{k}'v_4, \{\mathbf{k}+\mathbf{Q}\}_{c_1}}$$

$$U = \begin{bmatrix} \frac{1}{\sqrt{2}} & \frac{1}{\sqrt{2}} & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \\ \frac{1}{\sqrt{2}} & -\frac{1}{\sqrt{2}} & 0 & 0 \end{bmatrix}$$

More on the discretization of the linear response problem...



$$\left(\hbar\omega \mathbb{1}_{N_{\mathbf{k}} \times N_{\mathbf{k}}} - \begin{bmatrix} R_{\{\mathbf{k}'_1 + \mathbf{Q}\}_{c_3, \mathbf{k}'_1 v_4}} & R_{\{\mathbf{k}'_2 + \mathbf{Q}\}_{c_3, \mathbf{k}'_2 v_4}} & \begin{matrix} \mathbf{k}' \\ \rightarrow \end{matrix} \\ R_{\{\mathbf{k}_1 + \mathbf{Q}\}_{c_1, \mathbf{k}_1 v_2}} & R_{\{\mathbf{k}_1 + \mathbf{Q}\}_{c_1, \mathbf{k}_1 v_2}} & \begin{matrix} \mathbf{k}' \\ \rightarrow \end{matrix} \\ R_{\{\mathbf{k}'_1 + \mathbf{Q}\}_{c_3, \mathbf{k}'_1 v_4}} & R_{\{\mathbf{k}'_2 + \mathbf{Q}\}_{c_3, \mathbf{k}'_2 v_4}} & \begin{matrix} \mathbf{k}' \\ \rightarrow \end{matrix} \\ R_{\{\mathbf{k}_2 + \mathbf{Q}\}_{c_1, \mathbf{k}_2 v_2}} & R_{\{\mathbf{k}_2 + \mathbf{Q}\}_{c_1, \mathbf{k}_2 v_2}} & \begin{matrix} \mathbf{k}' \\ \rightarrow \end{matrix} \\ \vdots & \vdots & \ddots \end{bmatrix} \right) \times \\
 \times \begin{bmatrix} \rho_{\{\mathbf{k}'_1 + \mathbf{Q}\}_{c_3, \mathbf{k}'_1 v_4}}^{(1)} \\ \rho_{\{\mathbf{k}'_2 + \mathbf{Q}\}_{c_3, \mathbf{k}'_2 v_4}}^{(1)} \\ \downarrow \mathbf{k}' \end{bmatrix} = \begin{bmatrix} \mathcal{J}_{\{\mathbf{k}_1 + \mathbf{Q}\}_{c_1, \mathbf{k}_1 v_2}} \\ \mathcal{J}_{\{\mathbf{k}_2 + \mathbf{Q}\}_{c_1, \mathbf{k}_2 v_2}} \\ \downarrow \mathbf{k} \end{bmatrix}$$

Electronic parameters:

- $e^2/\epsilon_0 = 10^4/55.3 \text{ eV}\text{\AA}$
- $\epsilon_g = 7.8 \text{ eV}$
- $t = 3.1 \text{ eV}$
- $a_0 = 1.42\sqrt{3} \text{ \AA}$
- $r_0 = 10 \text{ \AA}$

Numerical parameters:

- $N_k = 8649 \text{ } k\text{-points}$
- $|k_{\text{cutoff}}| = 1.5 \text{ \AA}$

Tamm-Dancoff Approx.

Linear regime

$$\rho(t) \approx \rho^{(0)} + \rho^{(1)}(t)$$

More on the TD Hartree-Fock mean-field theory...

Linear regime

$$\rho(t) \approx \rho^{(0)} + \rho^{(1)}(t)$$

Single-particle basis

$$h_{ac} = \epsilon_a \delta_{ac}$$

$$\rho_{ab}^{(0)} = f_a \delta_{ab}$$

More on the TD Hartree-Fock mean-field theory...

Linear regime

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$$\left(\hbar\omega \delta_{ab}^{\gamma\delta} - H_{ab}^{\gamma\delta} \right) \rho_{ab}^{(1)}(\omega) = J_{ab}(\omega)$$

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Effective two-particle Hamiltonian

$$H_{ab}^{\gamma\delta} = (\epsilon_a - \epsilon_b) \delta_{a\gamma} \delta_{\delta b} + (f_b - f_a) \left(V_{b\gamma}^{\delta a} - W_{b\gamma}^{a\delta} \right)$$

More on the TD Hartree-Fock mean-field theory...

Linear regime

$$\rho(t) \approx \rho^{(0)} + \rho^{(1)}(t)$$

Single-particle basis

$$\begin{aligned} h_{ac} &= \epsilon_a \delta_{ac} \\ \rho_{ab}^{(0)} &= f_a \delta_{ab} \end{aligned}$$

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$$H_{ab}^{\gamma\delta} = (\epsilon_a - \epsilon_b) \delta_{a\gamma} \delta_{\delta b} + (f_b - f_a) \left(V_{b\gamma}^{\delta a} - W_{b\gamma}^{a\delta} \right)$$

Source term

$$J_{ab}(\omega) = (f_b - f_a) B_{ab}^i F^i(\omega)$$

Zero temperature regime

At $T = 0K$, the occupational degree of freedom can only be classified as either occupied $|o\rangle$ or empty $|e\rangle$ meaning that $f_o = 1$ or $f_e = 0$.

More on the TD Hartree-Fock mean-field theory...

Zero temperature regime

At $T = 0K$, the occupational degree of freedom can only be classified as either occupied $|o\rangle$ or empty $|e\rangle$ meaning that $f_o = 1$ or $f_e = 0$.

$$\left(\hbar\omega \mathbb{1} - \begin{bmatrix} H_{e_1 e_2}^{e_3 e_4} & H_{e_1 e_2}^{e_3 o_4} & H_{e_1 e_2}^{o_3 e_4} & H_{e_1 e_2}^{o_3 o_4} \\ H_{e_1 o_2}^{e_3 e_4} & H_{e_1 o_2}^{e_3 o_4} & H_{e_1 o_2}^{o_3 e_4} & H_{e_1 o_2}^{o_3 o_4} \\ H_{o_1 e_2}^{e_3 e_4} & H_{o_1 e_2}^{e_3 o_4} & H_{o_1 e_2}^{o_3 e_4} & H_{o_1 e_2}^{o_3 o_4} \\ H_{o_1 o_2}^{e_3 e_4} & H_{o_1 o_2}^{e_3 o_4} & H_{o_1 o_2}^{o_3 e_4} & H_{o_1 o_2}^{o_3 o_4} \end{bmatrix} \right) \begin{bmatrix} \rho_{e_3 e_4}^{(1)}(\omega) \\ \rho_{e_3 o_4}^{(1)}(\omega) \\ \rho_{o_3 e_4}^{(1)}(\omega) \\ \rho_{o_3 o_4}^{(1)}(\omega) \end{bmatrix} = \begin{bmatrix} \mathcal{J}_{e_1 e_2}(\omega) \\ \mathcal{J}_{e_1 o_2}(\omega) \\ \mathcal{J}_{o_1 e_2}(\omega) \\ \mathcal{J}_{o_1 o_2}(\omega) \end{bmatrix}$$

More on the TD Hartree-Fock mean-field theory

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$$\left(\hbar\omega \mathbb{1} - \begin{bmatrix} H_{e_1 e_2}^{e_3 e_4} & 0 & 0 & 0 \\ H_{e_1 o_2}^{e_3 e_4} & H_{e_1 o_2}^{e_3 o_4} & H_{e_1 o_2}^{o_3 e_4} & H_{e_1 o_2}^{o_3 o_4} \\ H_{o_1 e_2}^{e_3 e_4} & H_{o_1 e_2}^{e_3 o_4} & H_{o_1 e_2}^{o_3 e_4} & H_{o_1 e_2}^{o_3 o_4} \\ 0 & 0 & 0 & H_{o_1 o_2}^{o_3 o_4} \end{bmatrix} \right) \begin{bmatrix} \rho_{e_3 e_4}^{(1)}(\omega) \\ \rho_{e_3 o_4}^{(1)}(\omega) \\ \rho_{o_3 e_4}^{(1)}(\omega) \\ \rho_{o_3 o_4}^{(1)}(\omega) \end{bmatrix} = \begin{bmatrix} 0 \\ \mathcal{J}_{e_1 o_2}(\omega) \\ \mathcal{J}_{o_1 e_2}(\omega) \\ 0 \end{bmatrix}$$

Zero temperature regime

At $T = 0K$, the occupational degree of freedom can only be classified as either occupied $|o\rangle$ or empty $|e\rangle$ meaning that $f_o = 1$ or $f_e = 0$.

$$\left(\hbar\omega \mathbb{1} - \begin{bmatrix} H_{e_1 o_2}^{e_3 o_4} & H_{e_1 o_2}^{o_4 e_3} \\ H_{o_2 e_1}^{e_3 o_4} & H_{o_2 e_1}^{o_4 e_3} \end{bmatrix} \right) \begin{bmatrix} \rho_{e_3 o_4}^{(1)}(\omega) \\ \rho_{o_4 e_3}^{(1)}(\omega) \end{bmatrix} = \begin{bmatrix} \mathcal{J}_{e_1 o_2}(\omega) \\ \mathcal{J}_{o_2 e_1}(\omega) \end{bmatrix}$$

Zero temperature regime

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$$\left(\hbar\omega \mathbb{1} - \begin{bmatrix} H_{e_1 o_2}^{e_3 o_4} & H_{e_1 o_2}^{o_4 e_3} \\ H_{o_2 e_1}^{e_3 o_4} & H_{o_2 e_1}^{o_4 e_3} \end{bmatrix} \right) \begin{bmatrix} \rho_{e_3 o_4}^{(1)}(\omega) \\ \rho_{o_4 e_3}^{(1)}(\omega) \end{bmatrix} = \begin{bmatrix} \mathcal{J}_{e_1 o_2}(\omega) \\ \mathcal{J}_{o_2 e_1}(\omega) \end{bmatrix}$$

$$H_{o_1 e_2}^{o_4 e_4} = - (H_{e_1 o_2}^{e_3 o_4})^* \quad \text{and} \quad H_{o_2 e_1}^{e_4 o_3} = - (H_{e_1 o_2}^{o_3 e_4})^\dagger$$